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INFORMATION DISCLOSURE					Filing Date	February 16, 2000	
STATEMENT BY APPLICANT					First Named Inventor	Michel Piché et al.	
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Sheet 1 of		3		Attorney Docket Number	6013-63us JA/mb		

				U.S. PATENT DOCU	MENTS	
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Sheet	2	of	3	Attorney Docket Number	6013-63us JA/mb

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS							
xaminer Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T²				
AL	-	Actively Mode-locked GalnAsP Laser with Subpicosecond Output, S.W. Corzine et al., Appl. Phys. Lett., Vol. 52, No. 5, Feb. 1, 1988, pp. 348-350.					
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Group Art Unit

Examiner Name

Attorney Docket Number

2877

Armando Rodriguez

6013-63us JA/mb

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
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